

TOSHIBA BI-DIRECTIONAL TRIODE THYRISTOR SILICON PLANAR TYPE

SM3G45,SM3J45

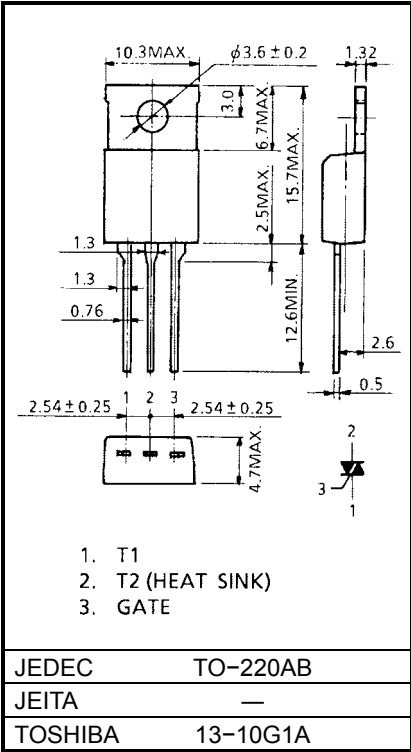
AC POWER CONTROL APPLICATIONS

- Repetitive Peak Off-State Voltage : $V_{DRM} = 400, 600V$
- R.M.S ON-State Current : $I_T (RMS) = 3A$
- High Commutating (dv / dt)

MAXIMUM RATINGS

CHARACTERISTIC		SYMBOL	RATING	UNIT
Repetitive Peak Off-State Voltage	SM3G45	V_{DRM}	400	V
	SM3J45		600	
R.M.S On-State Current (Full Sine Waveform $T_c = 111^{\circ}C$)		$I_T (RMS)$	3	A
Peak One Cycle Surge On-State Current (Non-Repetitive)		I_{TSM}	30 (50Hz)	A
			33 (60Hz)	
I^2t Limit Value		I^2t	4.5	A^2s
Critical Rate of Rise of On-State Current		di / dt	50	A / μs
Peak Gate Power Dissipation		P_{GM}	5	W
Average Gate Power Dissipation		$P_G (AV)$	0.5	W
Peak Gate Voltage		V_{GM}	10	V
Peak Gate Current		I_{GM}	2	A
Junction Temperature		T_j	-40~125	$^{\circ}C$
Storage Temperature Range		T_{stg}	-40~125	$^{\circ}C$

Unit: mm

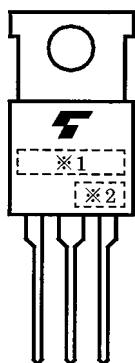


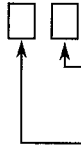
Weight: 2.0g

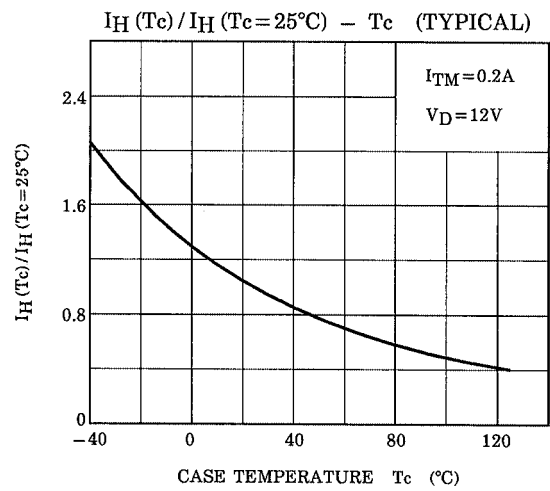
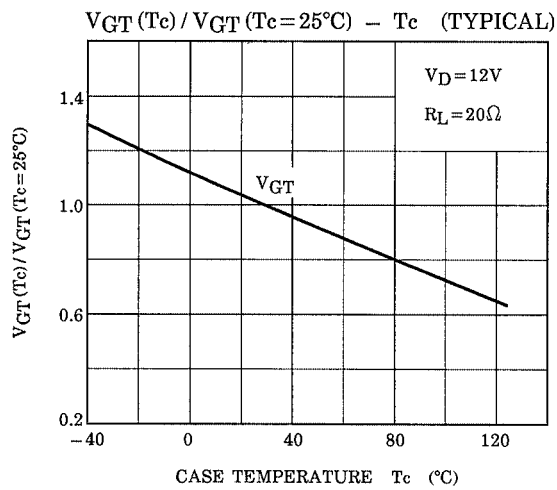
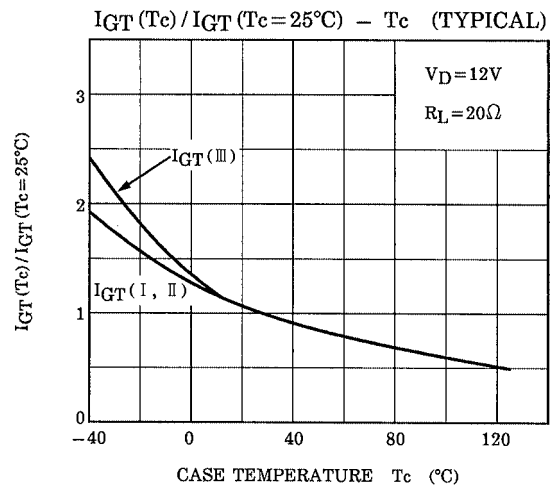
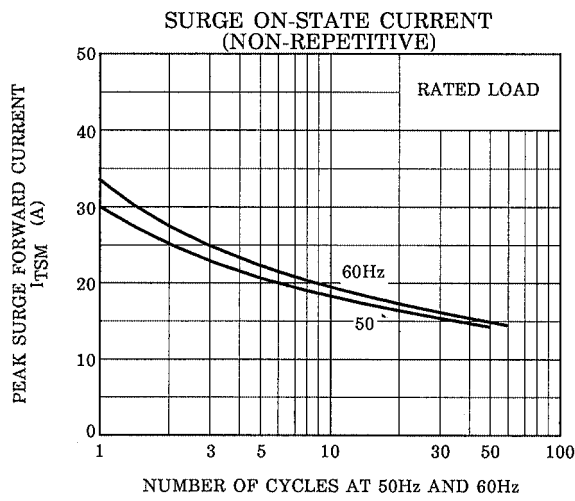
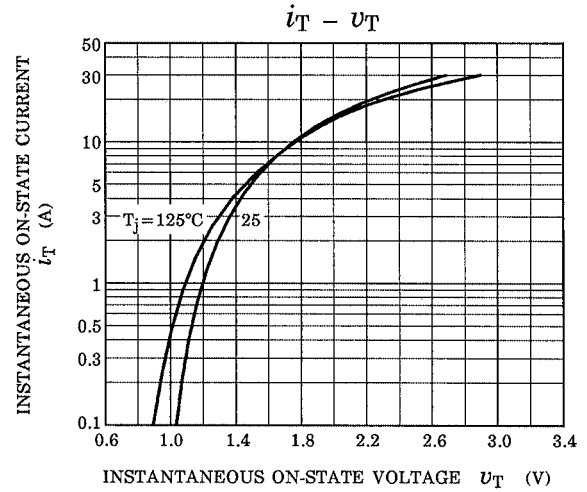
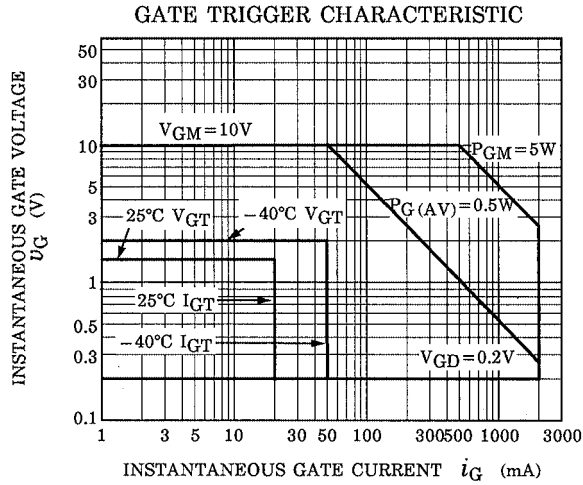
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

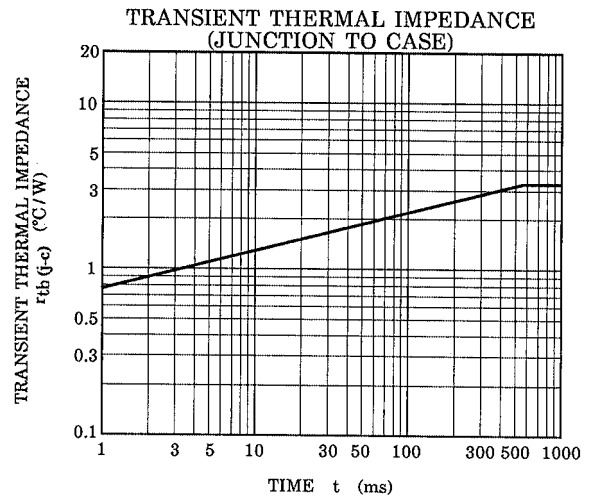
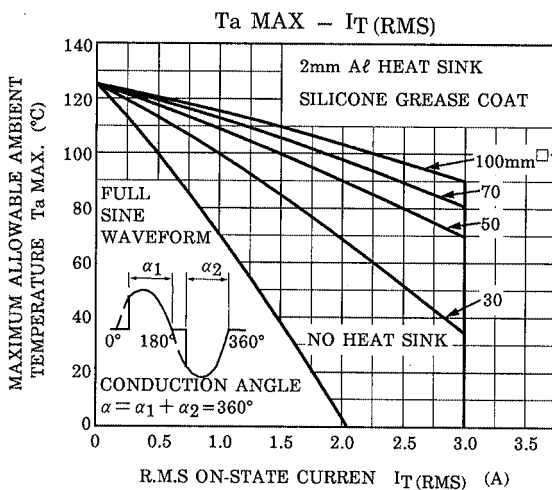
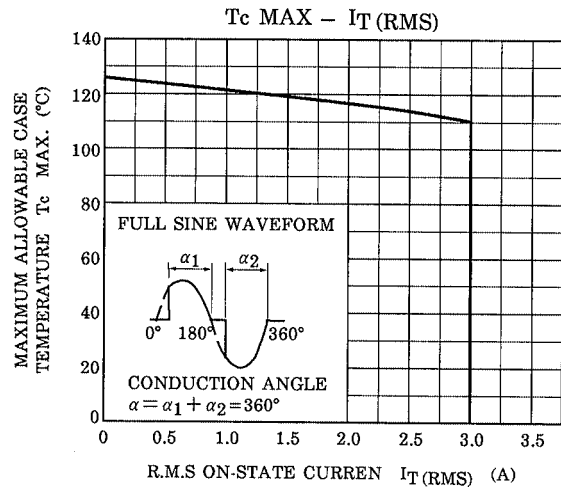
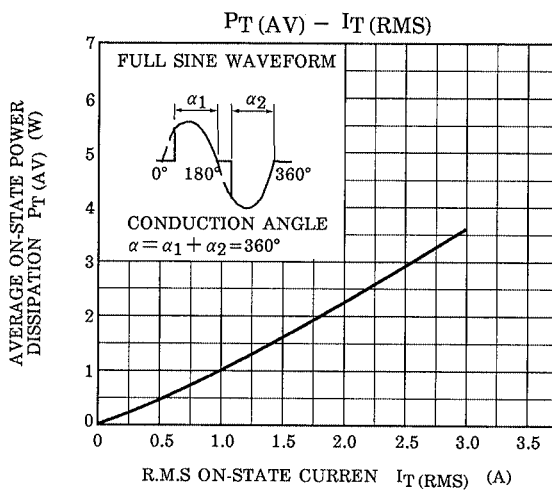
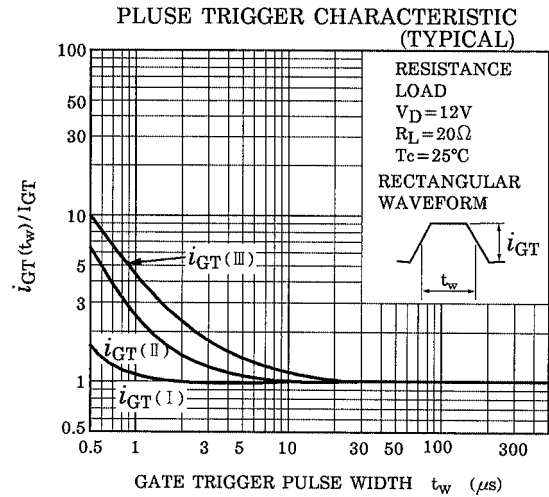
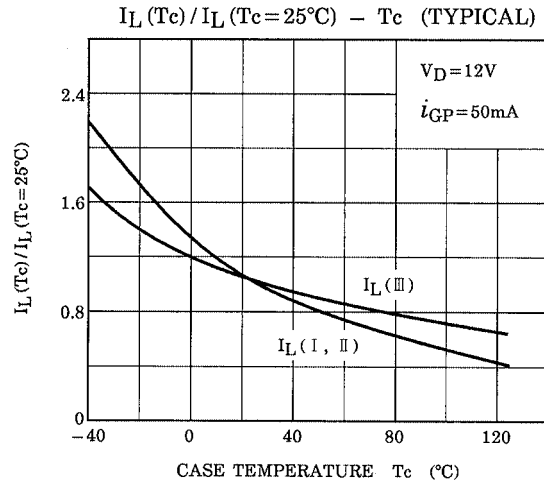
CHARACTERISTIC		SYMBOL	TEST CONDITION		MIN	TYP.	MAX	UNIT
Repetitive Peak Off-State Current		I_{DRM}	$V_{DRM} = \text{Rated}$		—	—	20	μA
Gate Trigger Voltage	I	V_{GT}	$V_D = 12\text{V}$ $R_L = 20\Omega$	T2 (+), Gate (+)	—	—	1.5	V
	II			T2 (+), Gate (-)	—	—	1.5	
	III			T2 (-), Gate (-)	—	—	1.5	
	IV			T2 (-), Gate (+)	—	—	—	
Gate Trigger Current	I	I_{GT}	$V_D = 12\text{V}$ $R_L = 20\Omega$	T2 (+), Gate (+)	—	—	20	mA
	II			T2 (+), Gate (-)	—	—	20	
	III			T2 (-), Gate (-)	—	—	20	
	IV			T2 (-), Gate (+)	—	—	—	
Peak On-State Voltage		V_{TM}	$I_{TM} = 4.5\text{A}$		—	—	1.5	V
Gate Non-Trigger Voltage		V_{GD}	$V_D = \text{Rated}$, $T_c = 125^\circ\text{C}$		0.2	—	—	V
Holding Current		I_H	$V_D = 12\text{V}$, $I_{TM} = 0.2\text{A}$		—	—	30	mA
Critical Rate of Rise of Off-State Voltage		dv / dt	$V_D = V_{DRM}$, $T_j = 125^\circ\text{C}$ Exponential Rise		100	—	—	V / μs
Critical Rate of Rise of Off-State Voltage at Commutation		$(dv / dt)_c$	$V_{DRM} = 400\text{V}$, $(di / dt)_c = -2\text{A} / \text{ms}$ $T_j = 125^\circ\text{C}$		10	—	—	V / μs
Thermal Resistance		$R_{th(j-c)}$	Junction to Case, AC		—	—	3.3	$^\circ\text{C} / \text{W}$

MARKING



NUMBER	SYMBOL		MARK
* 1	TYPE	SM3G45	M3G45
		SM3J45	M3J45
* 2	Lot Number  Month (Starting from Alphabet A) Year (Last Decimal Digit of the Current Year)		Example 8A : January 1998 8B : February 1998 8L : December 1998





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